

### Absolute Maximum Ratings (@TA = 25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	350	V
Collector-Emitter Voltage	$V_{CEO}$	350	V
Emitter-Base Voltage	$V_{EBO}$	5.0	V
Continuous Base Current	lΒ	25	mA
Continuous Collector Current	Ic	500	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	300	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	417	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)					
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	350	_	V	$I_C = 100\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	350	_	V	$I_C = 1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	5.0	_	V	$I_E = 10\mu A, I_C = 0$
Collector Cutoff Current	I <sub>CBO</sub>	_	50	nA	$V_{CB} = 250V, I_E = 0$
Collector Cutoff Current	I <sub>EBO</sub>	_	50	nA	$V_{CE} = 5V, I_{C} = 0$
ON CHARACTERISTICS (Note 6)					
DC Current Gain	h <sub>FE</sub>	20 30 30 20 15		_	$\begin{split} & I_{C} = 1.0 \text{mA},  V_{CE} = 10 \text{V} \\ & I_{C} = 10 \text{mA},  V_{CE} = 10 \text{V} \\ & I_{C} = 30 \text{mA},  V_{CE} = 10 \text{V} \\ & I_{C} = 50 \text{mA},  V_{CE} = 10 \text{V} \\ & I_{C} = 100 \text{mA},  V_{CE} = 10 \text{V} \end{split}$
Collector-Emitter Saturation Voltage	VCE(SAT)	_ _ _	0.30 0.35 0.50 1.0	V	$I_C = 10\text{mA}, I_B = 1.0\text{mA}$ $I_C = 20\text{mA}, I_B = 2.0\text{mA}$ $I_C = 30\text{mA}, I_B = 3.0\text{mA}$ $I_C = 50\text{mA}, I_B = 5.0\text{mA}$
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	 	0.75 0.80 0.90	V	$I_C = 10mA$ , $I_B = 1.0mA$ $I_C = 20mA$ , $I_B = 2.0mA$ $I_C = 30mA$ , $I_B = 3.0mA$
Base-Emitter On Voltage	V <sub>BE(ON)</sub>		2.0	V	$I_C = 100 \text{mA}, V_{CE} = 10 \text{V}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C <sub>obo</sub>		7.0	pF	$V_{CB} = 20V, f = 1.0MHz, I_E = 0$
Transition Frequency	f⊤	50	_	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 20mA

lotes: 5. For a device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper; device is measured under still air conditions whilst operating in a steady-state.

<sup>6.</sup> Short duration pulse test used to minimize self-heating effect.



### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

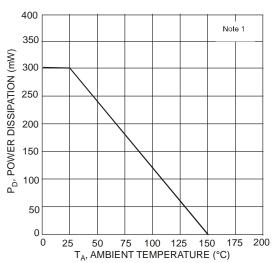


Fig. 1, Max Power Dissipation vs. Ambient Temperature

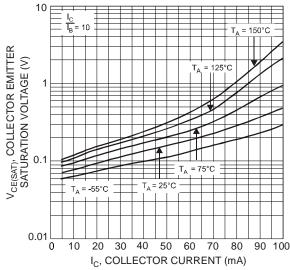


Fig. 3, Collector-Emitter Saturation Voltage vs. Collector Current

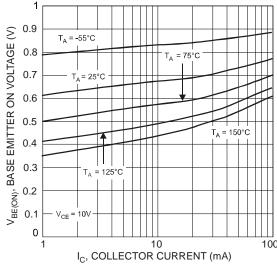


Fig. 5, Base-Emitter On Voltage vs. Collector Current

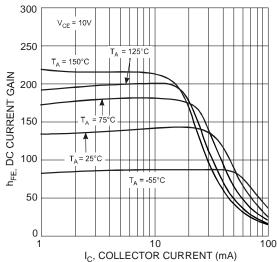


Fig. 2, DC Current Gain vs. Collector Current

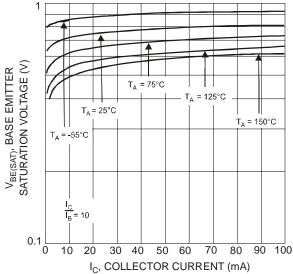


Fig. 4, Base Emitter Saturation Voltage vs. Collector Current

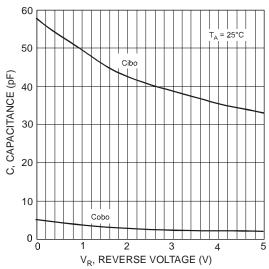


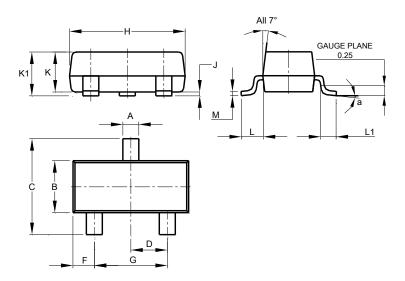
Fig. 6, Capacitance vs. Reverse Voltage



### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

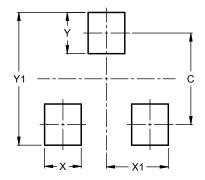


SOT23				
Dim	Min	Max	Тур	
Α	0.37	0.51	0.40	
В	1.20	1.40	1.30	
С	2.30	2.50	2.40	
D	0.89	1.03	0.915	
F	0.45	0.60	0.535	
G	1.78	2.05	1.83	
Н	2.80	3.00	2.90	
J	0.013	0.10	0.05	
K	0.890	1.00	0.975	
<b>K</b> 1	0.903	1.10	1.025	
L	0.45	0.61	0.55	
L1	0.25	0.55	0.40	
М	0.085	0.150	0.110	
а	0°	8°		
All Dimensions in mm				

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23



Dimensions	Value (in mm)	
С	2.0	
Х	0.8	
X1	1.35	
Y	0.9	
Y1	2.9	



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